Berry curvature of Bloch states

- A. Basics of Bloch state
- B. Electric response of Bloch state
- C. Quantum Hall effect

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D. Gauge choice of Bloch state

Basics

Basics

\n• Lattice Hamiltonian

\n
$$
H = \frac{p^2}{2m} + V_L(\mathbf{r}), \text{ with } V_L(\mathbf{r} + \mathbf{R}) = V_L(\mathbf{r})
$$
\n• Lattice translation operator

\n
$$
T_R \psi(\mathbf{r}) = \psi(\mathbf{r} + \mathbf{R})
$$
\n
$$
T_R H(\mathbf{r}) \psi(\mathbf{r}) = H(\mathbf{r}) T_R \psi(\mathbf{r})
$$
\n• Simultaneous eigenstates (Bloch states)

\n
$$
(H\psi) = \psi(\mathbf{r} + \mathbf{R}) \qquad \text{the}
$$
\n
$$
H\psi = \psi(\mathbf{r} + \mathbf{R}) \qquad \text{the}
$$

(Bloch states)

$$
H\psi = \varepsilon \psi, \quad |c_{\mathbf{R}}|=1
$$

$$
T_{\mathbf{R}}\psi = c_{\mathbf{R}}\psi,
$$

an
\n
$$
T_{\mathbf{R}}T_{\mathbf{R}'} = T_{\mathbf{R}'}T_{\mathbf{R}} = T_{\mathbf{R}+\mathbf{R}'}
$$
\nwith $V_L(\mathbf{r} + \mathbf{R}) = V_L(\mathbf{r})$
\n⇒ $c_{\mathbf{R}} = e^{i\mathbf{k} \cdot \mathbf{R}}$
\nto
\n $c_{\mathbf{R}} = e^{i\mathbf{k} \cdot \mathbf{R}}$
\nTo
\n $H \psi_{\varepsilon \mathbf{k}} = \varepsilon \psi_{\varepsilon \mathbf{k}}$,
\n $T_{\mathbf{R}} \psi_{\varepsilon \mathbf{k}} = e^{i\mathbf{k} \cdot \mathbf{R}} \psi_{\varepsilon \mathbf{k}}$.
\n $(\mathbf{r})T_{\mathbf{R}} \psi(\mathbf{r})$
\nwrite $\psi_{\varepsilon \mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k} \cdot \mathbf{r}} u_{\varepsilon \mathbf{k}}(\mathbf{r})$
\nent
\n $\psi_{\varepsilon \mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k} \cdot \mathbf{r}} u_{\varepsilon \mathbf{k}}(\mathbf{r})$
\n $|c_{\mathbf{R}}| = 1$
\n∴ The Bloch wave differs from the plane
\nwave of free electrons only by a periodic
\nmodulation.
\n• $u_{\varepsilon \mathbf{k}}(\mathbf{r})$ contains, in one unit cell, all info of $\psi_{\varepsilon \mathbf{k}}(\mathbf{r})$

- wave of free electrons only by a periodic modulation.
- $u_{\rm sk}(r)$ contains, in one unit cell, all info of $\psi_{\rm sk}(r)$

Schroedinger eq. for $u_{ek}(r)$

Schroedinger eq. for
$$
u_{ek}(r)
$$

\n
$$
\tilde{H}_{k}(r) u_{\varepsilon k} = \varepsilon u_{\varepsilon k}
$$
\n
$$
\tilde{H}_{k}(r) \equiv e^{-i\mathbf{k} \cdot \mathbf{r}} H(r) e^{i\mathbf{k} \cdot \mathbf{r}}
$$
\n
$$
= \frac{1}{2m} (\mathbf{p} + \hbar \mathbf{k})^2 + V_L(\mathbf{r})
$$
\n
$$
u_{\varepsilon k}(r + \mathbf{R}) = e^{i\mathbf{k} \cdot \mathbf{R}}
$$
\nSolve diff eq with with PBC

\n
$$
u_{\varepsilon k}(r + \mathbf{R}) = u_{\varepsilon k}(r)
$$
\nSince the two Bloch states ψ same Schrödinger equation (v) same boundary condition (E can differ (for non-degenerate))

$$
u_{\varepsilon \mathbf{k}}(\mathbf{r} + \mathbf{R}) = u_{\varepsilon \mathbf{k}}(\mathbf{r})
$$

 $\tilde{H}_{\mathbf{k}}(\mathbf{r})u_{n\mathbf{k}}=\varepsilon_{n\mathbf{k}}u_{n\mathbf{k}}$ Band index n , Bloch momentum \boldsymbol{k}

$$
\psi_{n\mathbf{k}}(\mathbf{r} + \mathbf{R}) = e^{i\mathbf{k} \cdot \mathbf{R}} \psi_{n\mathbf{k}}(\mathbf{r})
$$

$$
e^{i\mathbf{G} \cdot \mathbf{R}} = 1
$$

$$
\psi_{n\mathbf{k} + \mathbf{G}}(\mathbf{r} + \mathbf{R}) = e^{i\mathbf{k} \cdot \mathbf{R}} \psi_{n\mathbf{k} + \mathbf{G}}(\mathbf{r})
$$

Discrete energy levels can differ (for non-degenerate states) at most by a phase factor $\phi(\mathbf{k})$. $\psi_{n\mathbf{k}}(\mathbf{r} + \mathbf{R}) = e^{i\mathbf{k} \cdot \mathbf{R}} \psi_{n\mathbf{k}}(\mathbf{r})$
 $e^{i\mathbf{G} \cdot \mathbf{R}} = 1$
 $\Rightarrow \psi_{n\mathbf{k}+\mathbf{G}}(\mathbf{r} + \mathbf{R}) = e^{i\mathbf{k} \cdot \mathbf{R}} \psi_{n\mathbf{k}+\mathbf{G}}(\mathbf{r})$

Since the two Bloch states $\psi_{n\mathbf{k}}$ and $\psi_{n\mathbf{k}+\mathbf{G}}$ satisf

$$
\psi_{n\mathbf{k}+\mathbf{G}} = \psi_{n\mathbf{k}}
$$

Not applicable to topological state, e.g., quantum Hall state (this is called topological obstruction)

Berry curvature in Bloch state

Berry curvature in Bloch state

\n\n- Cell-periodic Bloch state
\n- Geil-periodic Bloch state
\n- Spa
\n- $$
\tilde{H}_{\mathbf{k}}(\mathbf{r})u_{n\mathbf{k}}(\mathbf{r}) = \varepsilon_{n\mathbf{k}}u_{n\mathbf{k}}(\mathbf{r}) \qquad u_{n\mathbf{k}}(\mathbf{r})
$$
\n
$$
\tilde{H}_{\mathbf{k}}(\mathbf{r}) = e^{-i\mathbf{k}\cdot\mathbf{r}}H(\mathbf{r})e^{i\mathbf{k}\cdot\mathbf{r}} \qquad \therefore \mathbf{A}_{n}(\mathbf{k})
$$
\n
$$
= \frac{1}{2m}(\mathbf{p} + \hbar \mathbf{k})^{2} + V_{L}(\mathbf{r}) \qquad \mathbf{F}_{n}(\mathbf{k})
$$
\n
\n- Berry connection
\n- $$
\mathbf{A}_{n}(\mathbf{k}) = i\langle u_{n\mathbf{k}}| \frac{\partial}{\partial \mathbf{k}} |u_{n\mathbf{k}}\rangle \qquad u_{n\mathbf{k}}(\mathbf{r})
$$
\n
\n- Berry curvature
\n- $$
\mathbf{F}_{n}(\mathbf{k}) = \nabla_{\mathbf{k}} \times \mathbf{A}_{n}(\mathbf{k})
$$
\n
$$
\frac{\partial u_{n\mathbf{k}}}{\partial u_{n\mathbf{k}}} = \frac{\partial u_{n\mathbf{k}}}{\partial u_{n\mathbf{k}}}.
$$
\n
\n

Berry curvature in Bloch state

\n\n- Cell-periodic Bloch state
\n- Space inversion
\n- $$
\tilde{H}_{\mathbf{k}}(\mathbf{r})u_{n\mathbf{k}}(\mathbf{r}) = \varepsilon_{n\mathbf{k}}u_{n\mathbf{k}}(\mathbf{r})
$$
\n- $$
\tilde{H}_{\mathbf{k}}(\mathbf{r}) = e^{-i\mathbf{k}\cdot\mathbf{r}}H(\mathbf{r})e^{i\mathbf{k}\cdot\mathbf{r}}
$$
\n- $$
\tilde{H}_{\mathbf{k}}(\mathbf{r}) = e^{-i\mathbf{k}\cdot\mathbf{r}}H(\mathbf{r})e^{i\mathbf{k}\cdot\mathbf{r}}
$$
\n- $$
\tilde{H}_{n}(\mathbf{k}) = i\langle u_{n-\mathbf{k}}|\frac{\partial}{\partial \mathbf{k}}|u_{n-\mathbf{k}}\rangle = -\mathbf{A}_{n}(-\mathbf{k})
$$
\n- $$
= \frac{1}{2m}(\mathbf{p} + \hbar\mathbf{k})^{2} + V_{L}(\mathbf{r})
$$
\n- $$
\mathbf{F}_{n}(\mathbf{k}) = \nabla_{\mathbf{k}} \times [-\mathbf{A}_{n}(-\mathbf{k})] = \mathbf{F}_{n}(-\mathbf{k})
$$
\n
\nBerry connection

\n\n- Time reversal
\n
\n
$$
\mathbf{A}_{n}(\mathbf{k}) = i\langle u_{n\mathbf{k}}|\frac{\partial}{\partial \mathbf{k}}|u_{n\mathbf{k}}\rangle
$$

\n\n- $$
u_{n\mathbf{k}}(\mathbf{r}) \rightarrow u_{n-\mathbf{k}}^{*}(\mathbf{r}) = u_{n\mathbf{k}}(\mathbf{r}),
$$
\n

$$
\mathbf{A}_n(\mathbf{k}) = i \langle u_{n\mathbf{k}} | \frac{\partial}{\partial \mathbf{k}} | u_{n\mathbf{k}} \rangle
$$

$$
\mathbf{F}_n(\mathbf{k}) = \nabla_{\mathbf{k}} \times \mathbf{A}_n(\mathbf{k})
$$

$$
= i \langle \frac{\partial u_{n\mathbf{k}}}{\partial \mathbf{k}} | \times | \frac{\partial u_{n\mathbf{k}}}{\partial \mathbf{k}}
$$

$$
u_{n\mathbf{k}}(\mathbf{r}) \rightarrow u_{n-\mathbf{k}}^{*}(\mathbf{r}) = u_{n\mathbf{k}}(\mathbf{r}),
$$

\n
$$
\mathbf{A}_{n}(\mathbf{k}) = i \langle u_{n-\mathbf{k}}^{*} | \frac{\partial}{\partial \mathbf{k}} | u_{n-\mathbf{k}}^{*} \rangle
$$

\n
$$
= -i \langle u_{n-\mathbf{k}} | \frac{\partial}{\partial \mathbf{k}} | u_{n-\mathbf{k}} \rangle = \mathbf{A}_{n}(-\mathbf{k})
$$

\n
$$
\mathbf{F}_{n}(\mathbf{k}) = \nabla_{\mathbf{k}} \times \mathbf{A}_{n}(-\mathbf{k}) = -\mathbf{F}_{n}(-\mathbf{k})
$$

Under one-band approximation (same as the adiabatic approximation)

Velocity of electron in an electric field,

$$
\mathbf{v}_n(\mathbf{k}) = \frac{1}{\hbar} \frac{\partial \varepsilon_{n\mathbf{k}}}{\partial \mathbf{k}} + \frac{e}{\hbar} \mathbf{E} \times \mathbf{F}_n(\mathbf{k})
$$

BC-induced velocity, aka anomalous velocity

Pf: Choose time-dependent gauge

$$
\mathbf{E} = -\partial \mathbf{A}/\partial t, \, \mathbf{A} = -\mathbf{E}t
$$

$$
\begin{aligned}\n\widehat{H}_{\mathbf{k}_0}^{\mathbf{E}} &= \frac{(\mathbf{p} + \hbar \mathbf{k}_0 - e\mathbf{E}t)^2}{2m} + V_L(\mathbf{r}) = \tilde{H}_{\mathbf{k}(t)} \\
\mathbf{k}(t) &= \mathbf{k}_0 - e\mathbf{E}t/\hbar.\n\end{aligned}
$$

To the 0-th order, just replace $|u_{n\mathbf{k}}\rangle$ with $|u_{n\mathbf{k}(t)}\rangle$ and $\widetilde{H}_{\mathbf{k}(t)}|u_{n\mathbf{k}(t)}\rangle = \varepsilon_{n\mathbf{k}(t)}|u_{n\mathbf{k}(t)}\rangle$

To the first-order (see Prob. 1),

 $|u_{n\mathbf{k}}^{(1)}\rangle = |u_{n\mathbf{k}}\rangle - i\hbar \sum_{n'(\neq n)} \frac{|u_{n'\mathbf{k}}\rangle \langle u_{n'\mathbf{k}}| \frac{\partial}{\partial t} |u_{n\mathbf{k}}\rangle}{\varepsilon_{n\mathbf{k}} - \varepsilon_{n'\mathbf{k}}}$ $\mathbf{v}_n(\mathbf{k}) = \langle \psi_{n\mathbf{k}}^{(1)} | \frac{\mathbf{p}}{m} | \psi_{n\mathbf{k}}^{(1)} \rangle$ $= \langle u_{n\mathbf{k}}^{(1)} | \frac{\mathbf{p} + \hbar \mathbf{k}}{m} | u_{n\mathbf{k}}^{(1)} \rangle$ $= \langle u_{n\mathbf{k}}^{(1)} | \frac{\partial \tilde{H}_{\mathbf{k}}}{\partial \partial \mathbf{k}} | u_{n\mathbf{k}}^{(1)} \rangle.$ $\mathbf{v}_n(\mathbf{k}) = \langle u_{n\mathbf{k}} | \frac{\partial H_{\mathbf{k}}}{\hbar \partial \mathbf{k}} | u_{n\mathbf{k}} \rangle$ $- i \sum_{n'(\neq n)} \left(\frac{\langle u_{n\mathbf{k}} | \frac{\partial H_{\mathbf{k}}}{\partial \mathbf{k}} | u_{n'\mathbf{k}} \rangle \langle u_{n'\mathbf{k}} | \frac{\partial u_{n\mathbf{k}}}{\partial t} \rangle}{\varepsilon_{n\mathbf{k}} - \varepsilon_{n'\mathbf{k}}} - c.c. \right)$ $\mathbf{v}_n(\mathbf{k})$ $= \frac{\partial \varepsilon_{n\mathbf{k}}}{\partial \mathbf{k}} - i \left(\left\langle \frac{\partial u_{n\mathbf{k}}}{\partial \mathbf{k}} \Big| \frac{\partial u_{n\mathbf{k}}}{\partial t} \right\rangle - \left\langle \frac{\partial u_{n\mathbf{k}}}{\partial t} \Big| \frac{\partial u_{n\mathbf{k}}}{\partial \mathbf{k}} \right\rangle \right)$ $= \frac{\partial \varepsilon_{n\mathbf{k}}}{\hbar \partial \mathbf{k}} - \dot{\mathbf{k}} \times \mathbf{F}_n.$

6

• Current density
$$
J_x = -\frac{e}{L^2} \sum_{nk} f(\varepsilon_{nk}) v_{nx}(\mathbf{k})
$$

\t\t\t $= -\frac{e}{L^2} \sum_{nk} f(\varepsilon_{nk}) \frac{\partial \varepsilon_{nk}}{\hbar \partial k_x}$
\t\t\t $- \frac{e^2}{\hbar} \sum_{n} \frac{1}{L^2} \sum_{\mathbf{k}} f(\varepsilon_{nk}) F_{nz}(\mathbf{k}) E_y$
\t\t\t \cdot Hall conductivity $\sigma_{xy} = -\frac{e^2}{\hbar} \frac{1}{L^2} \sum_{n, \mathbf{k}} F_{nz}(\mathbf{k})$
\t\t\t $= -\frac{e^2}{\hbar} \sum_{n=1}^{N} \left(\frac{1}{2\pi} \int_{BZ} d^2 k F_{nz}(\mathbf{k}) \right)$
\tFor a filled band *n*, the integral over F_n is an integer (proof later)
\t• First Chern number $C_1^{(n)} = \frac{1}{2\pi} \int_{BZ} d^2 k F_{nz}(\mathbf{k}) \in Z$.
As a result, the Hall conductivity is quantized.
E.g., Quantum Hall effect, Chern insulator (anomalous Hall effect of 5,
\t~lattice version of QHE

 $(T=0)$

For a filled band *n*, the integral over
$$
F_n
$$
 is an integer (proof later)

• First Chern number
$$
C_1^{(n)} = \frac{1}{2\pi} \int_{BZ} d^2k F_{nz}(\mathbf{k}) \in Z
$$
.

As a result, the Hall conductivity is quantized.

Hall effect in 2-dimensional electron gas (2DEG)

- is frozen in the ground state \rightarrow 2DEG
- Landau levels (LLs)

[Integer] Quantum Hall effect (von Klitzing, 1980)

Hall resistivity and Hall conductivity at plateaus

$$
\rho_H=\frac{1}{n}\frac{h}{e^2}
$$

H

 $\sigma_{\scriptscriptstyle H}^{} =$

2

h

 $e^{\frac{1}{2}}$ \mathbf{n}

$$
h/e^2 = 25.81280745 \text{ k} \cdot \text{ohm}
$$

accurate to 10-9, a defined value after 1990

fine structure constant, $\alpha \equiv e^2/4\pi\varepsilon_0\hbar c$. [Note: After 2019, the values of e, h , and c are defined, and only ε_0 is uncertain.]

-
- Fermi energy lies inside an energy gap

(there is no plateaus in a clean 2DEG)

To observe IQHE, we need

-
-
- To observe IQHE, we need
• Two-dimensional electron system
• Breaking time-reversal symmetry
• Filled energy bands (insulator) with non-zero Chern numbers To observe IQHE, we need
▪ Two-dimensional electron system
▪ Breaking time-reversal symmetry
▪ Filled energy bands (insulator) with non-zero Chern n
▪ Landau levels (IOHF) To observe IQHE, we need
• Two-dimensional electron system
• Breaking time-reversal symmetry
• Filled energy bands (insulator) with non-zero Chern numbers
• Landau levels (IQHE)
• Bands with magnetization (OAHE) ← next c bserve IQHE, we need
wo-dimensional electron system
reaking time-reversal symmetry
illed energy bands (insulator) with non-zero Chern numbers
• Landau levels (IQHE)
• Bands with magnetization (QAHE) ← next chap
temp, high • Two-dimensional electron system

• Breaking time-reversal symmetry

• Filled energy bands (insulator) with non-zerc

• Landau levels (IQHE)

• Bands with magnetization (QAHE) \leftarrow ne

(Low temp, high *B* field are usua • Breaking time-reversal symmetry

• Filled energy bands (insulator) with non-z

• Landau levels (IQHE)

• Bands with magnetization (QAHE) \leftarrow

(Low temp, high *B* field are usually, but not necess

Examples of Macrosco • Filled energy bands (insulator) with non-zero Chern numbers
• Landau levels (IQHE)
• Bands with magnetization (QAHE) \Leftarrow next chap
(Low temp, high *B* field are usually, but not necessarily, required)
Examples of Macro
	-
	- bserve IQHE, we need

	wo-dimensional electron system

	reaking time-reversal symmetry

	Illed energy bands (insulator) with non-zero (

	 Landau levels (IQHE)

	 Bands with magnetization (QAHE) ← nex

	term high B field are

(Low temp, high B field are usually, but not necessarily, required)

Examples of Macroscopic Quantum Phenomena • Bands with magnetization (QAHE) \leftarrow
(Low temp, high *B* field are usually, but not necess
Examples of Macroscopic Quantum Phenon
• Superfluidity (Kapitsa, 1937)
• Quantum Hall effect (von Klitzing, 1980) < references.

-
-
- Landau levels (IQHE)

 Bands with magnetization (QAHE) \leftarrow next chap

(Low temp, high *B* field are usually, but not necessarily, required)

Examples of Macroscopic Quantum Phenomena

 Superfluidity (Kapitsa, 1937)

-

Quantum Hall Effect in 2D systems Quantum Hall Effect in 2D systems
• Si MOSFET (von Klitzing et al, 1980)
• GaAs heterojunction (Stormer, 1982)
• Graphene (Novoselov Science 2007) **Quantum Hall Effect in 2D systems

Need to break time-reversal symmetry

• Si MOSFET (von Klitzing et al, 1980)

• GaAs heterojunction (Stormer, 1982)

• Graphene (Novoselov, Science 2007)

• Polar oxide heterostructures**

Need to break time-reversal symmetry

-
-
-
- Quantum Hall Effect in 2D systems
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• Si MOSFET (von Klitzing et al, 1980)

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• Polar oxide heterostructures 99 Quantum Hall Effect in 2D systems

• Si MOSFET (von Klitzing et al, 1980)

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• Quantum Hall Effect in 2D systems

Need to break time-reversal symmetry

• Si MOSFET (von Klitzing et al, 1980)

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• Graphene (Novoselov, Science 2007)

• Polar oxide heterostructures (Effect in 2D systems

ime-reversal symmetry

(von Klitzing et al, 1980)

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neterostructures (Tsukazaki et al, Science 2007)

ver graphene (Lee et al, PRL 2011)

(Movva et a • Si MOSFET (von Klitzing et al, 1980)
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• GaAs heterojunction (Stormer, 1982)

• Graphene (Novoselov, Science 2007)

• Polar oxide heterostructures (Tsukazaki et

• Twisted bilayer graphene (Lee et al, PRL 2017)

• InSe (Band
-

過渡金屬硫化物

- Transition Metal | Twisted bilayer graphene (Lee et al, PRL 2011)
- Dichalcogenide \rightarrow TMD: WSe₂ (Movva et al, PRL 2017)
	-
	-
	-

Before proving that C_1 is an integer, $\,$ let's review $\,$

the Berry curvature of a spin-1/2 electron:

18 of the topological obstruction.

In Fig. 2(a), we see a loop C_1 near the north pole, and a loop C_2 near the south pole. The area inside C_1 is designated as S_1 ; the area outside is \overline{S}_1 . Similarly the area inside C_2 is S_2 , outside is \bar{S}_2 . It is not difficult to see that,

The LHS approaches 2π as C_2 shrinks to zero; while the last integral approaches 0. The inequalities arise because the Stokes theorem fails if **A** is singular in the domain of ₁₉ surface integration.

We can use two patches of gauge to avoid the singularity

$$
\int_{S^2} d^2 \mathbf{a} \cdot \mathbf{F}_{\pm}
$$
\n
$$
= \int_{S_N} d^2 \mathbf{a} \cdot \nabla \times \mathbf{A}_{\pm}^N + \int_{S_S} d^2 \mathbf{a} \cdot \nabla \times \mathbf{A}_{\pm}^S
$$
\n
$$
= \oint_{C_{\epsilon}} d\ell \cdot \mathbf{A}_{\pm}^N + \oint_{C_{-\epsilon}} d\mathbf{k} \cdot \mathbf{A}_{\pm}^S
$$
\n
$$
= \oint_{C_0} d\ell \cdot (\mathbf{A}_{\pm}^N - \mathbf{A}_{\pm}^S)
$$
\n
$$
= \mp \oint_{C_0} d\ell \cdot \frac{\partial \phi}{\partial \mathbf{B}} = \mp 2\pi.
$$
\nGauge S\n
$$
= \ell \int_{C_0} d\ell \cdot \frac{\partial \phi}{\partial \mathbf{B}} = \mp 2\pi.
$$

20 needs be quantized.The same analysis applies to the magnetic monopole in real space. So the flux of a magnetic monopole (or the monopole charge)

Now, back to the quantum Hall systemWhat is special about the QH Bloch state is that there exist nodal points in the BZ, where $u_{n\mathbf{k}_i} = 0$. Similar to the south pole in Fig. 2(a), the phase is ambiguous at \mathbf{k}_i , and the Berry connection $\mathbf{A}_n(\mathbf{k})$ is singular there (see Fig. 3(a)).

Assume there is only one singular point, then the line integral of $\mathbf{A}_n(\mathbf{k})$ around a small loop C enclosing \mathbf{k}_1 (and divided by 2π) equals the first Chern number (similar to the loop C_2 in Fig. 2(a)). It is sometimes called the vorticity of the singular point.

21

$$
C_1 = \frac{1}{2\pi} \int_{BZ} d^2k \ F_z(\vec{k})
$$
 is an integer
Pf: $u_{n\mathbf{k}}^{II} = e^{i\chi_{n\mathbf{k}}} u_{n\mathbf{k}}^{I}$ Gauge
transformation

$$
\blacktriangleright \mathbf{A}_n^{II}(\mathbf{k}) = \mathbf{A}_n^I(\mathbf{k}) - \frac{\partial \chi_n(\mathbf{k})}{\partial \mathbf{k}}
$$

Using two patches of gauge to avoid singularity

$$
\int_{BZ} d^2 \mathbf{k} \cdot \mathbf{F}_n
$$
\n
$$
= \int_{left} d^2 \mathbf{k} \cdot \nabla \times \mathbf{A}_n^I + \int_{right} d^2 \mathbf{k} \cdot \nabla \times \mathbf{A}_n^{II}
$$
\n
$$
= \oint_C d\mathbf{k} \cdot (\mathbf{A}_n^I - \mathbf{A}_n^{II})
$$
\n
$$
= \oint_C d\mathbf{k} \cdot \frac{\partial \chi_n}{\partial \mathbf{k}} = 2\pi \times \text{integer.}
$$

